

TV VERTICAL DEFLECTION BOOSTER

ADVANCE DATA

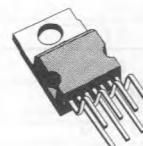
- POWER AMPLIFIER
- FLYBACK GENERATOR (105V PEAK)
- THERMAL PROTECTION
- CURRENT LIMITED TO GND

DESCRIPTION

Designed for Monitors and high performance TVs, the TDA8179 vertical deflection booster delivers fly-back voltages up to 105V.

The TDA8179 operates with supplies up to 50V and provides up to 2App output current to drive to yoke.

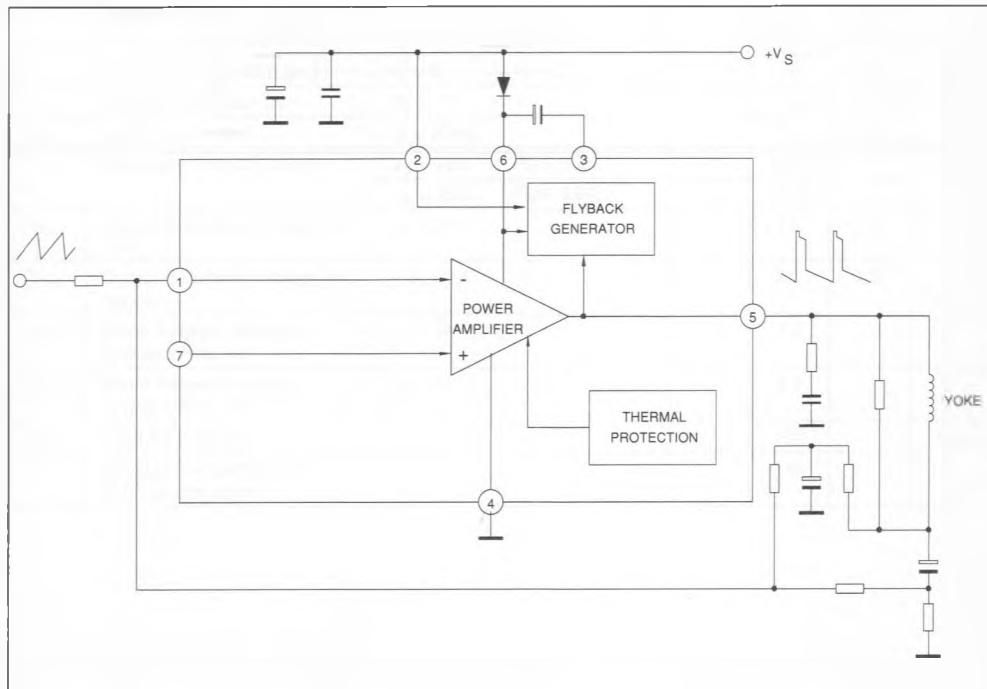
The TDA8179 is offered in HEPTAWATT package.

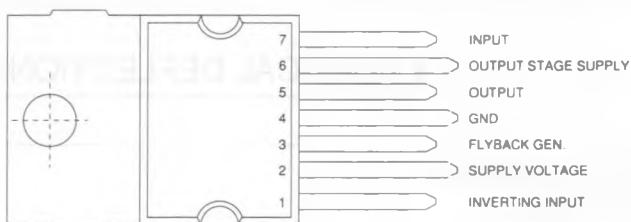
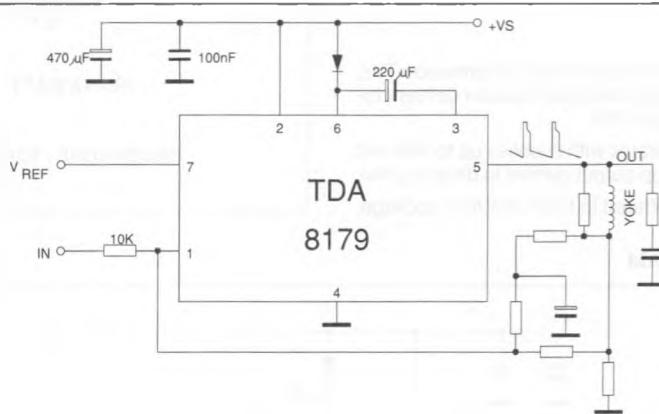


HEPTAWATT

ORDER CODE : TDA8179

BLOCK DIAGRAM



PIN CONNECTION (top view)**APPLICATION CIRCUIT**

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------|---|-------------|------|
| V_s | Supply Voltage (pin 2) | 50 | V |
| V_5, V_6 | Flyback Peak Voltage | 105 | V |
| V_1, V_7 | Amplifier Input Voltage | + V_s | |
| I_o | Output Peak Current (non repetitive, $t = 2\text{ms}$) | 2 | A |
| I_o | Output Peak Current at $f = 50$ or 60Hz $t \leq 10\mu\text{s}$ | 2 | A |
| I_o | Output Peak Current at $f = 50$ or 60Hz $t > 10\mu\text{s}$ | 1.8 | A |
| I_3 | Pin 3 DC at $V_5 < V_2$ | 100 | mA |
| I_3 | Pin 3 Peak Flyback Current at $f = 50$ or 60Hz , $t_{fly} \leq 1.5\text{ms}$ | 1.8 | A |
| P_{tot} | Total Power Dissipation at $T_{case} = 70^\circ\text{C}$ | 20 | W |
| T_{stg} | Storage Temperature | - 40 to 150 | °C |
| T_j | Junction Temperature | 0 to 150 | °C |

THERMAL DATA

| | | | | |
|--------------|----------------------------------|-----|---|------|
| $R_{th J-C}$ | Junction-case Thermal Resistance | Max | 4 | °C/W |
|--------------|----------------------------------|-----|---|------|

ELECTRICAL CHARACTERISTICS

(V₇ = 2.2V, V_s = 48V, T_{amb} = 25°C, unless otherwise specified) (refer to the test circuits)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|------------|---|--|------|-------|------|------|
| V_s | Operating Supply Voltage Range | | 10 | | 48 | V |
| I_2 | Pin 2 Quiescent Current | $I_3 = 0$ $I_5 = 0$ | | 10 | 20 | mA |
| I_6 | Pin 6 Quiescent Current | $I_3 = 0$ $I_5 = 0$ | | 20 | 40 | mA |
| I_1 | Amplifier bias Current | $V_1 = 1\text{V}$ | | - 0.2 | - 1 | μA |
| V_{3L} | Scanning Voltage | $I_3 = 20\text{mA}$ | | 1.3 | 1.8 | V |
| V_5 | Quiescent Output Voltage | $V_s = 48\text{V}$ $R_a = 3.9\text{K}\Omega$ | 24.2 | | | V |
| | | $V_s = 35\text{V}$ $R_a = 5.6\text{K}\Omega$ | 17.5 | | | |
| V_{5L} | Output Saturation Voltage to GND | $I_5 = 1\text{A}$ | | 1.2 | 1.5 | V |
| V_{5H} | Output Saturation Voltage to Supply | - $I_5 = 1\text{A}$ | | 2.2 | 2.8 | V |
| V_{D5-6} | Diode Forward Voltage between Pins 5-6 | $I_D = 1\text{A}$ | | 1.5 | | V |
| V_{D3-2} | Diode Forward Voltage between Pins 3-2 | $I_D = 1\text{A}$ | | 1.5 | | V |
| R_1 | Input Resistance | | | 200 | | KΩ |
| T_j | Junction Temperature for Thermal Shutdown | | | 140 | | °C |

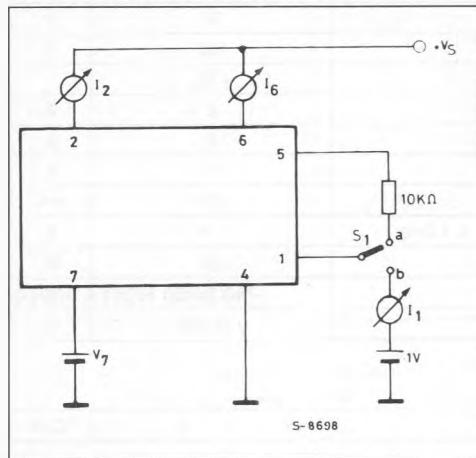
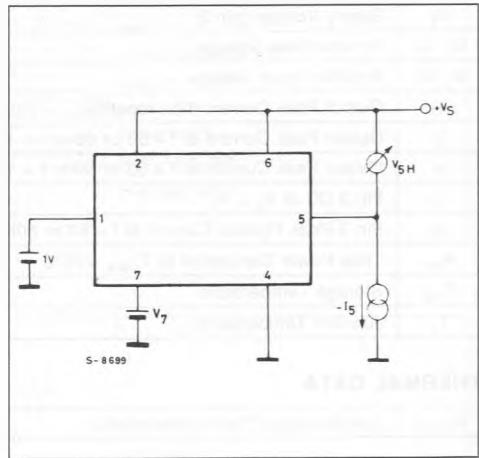
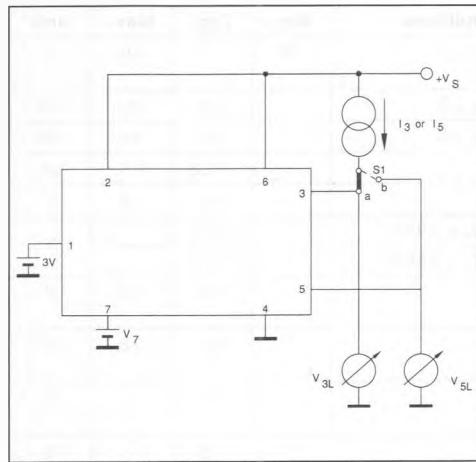
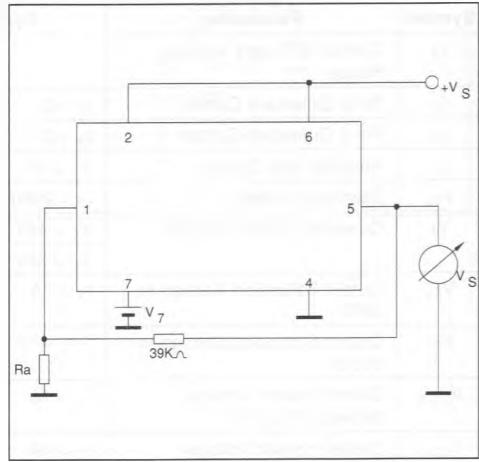
Figure 1 : DC Test Circuits.**Figure 1a : Measurement of I_2 ; I_2 ; I_6 .**S1 : (a) I_2 and I_6 ; (b) I_1 .**Figure 1b : Measurement of V_{5H} .****Figure 1c : Measurement of V_{3L} ; V_{5L} .**S1 : (a) V_{3L} ; (b) V_{5L} .**Figure 1d : Measurement of V_5 .**

Figure 2 : SOA of Each Output Power Transistor at 25°C amb.